

### N-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

BV <sub>SSS</sub>	R <sub>SS(ON)</sub> Typ	Ι <sub>S MAX</sub> Τ <sub>A</sub> = +25°C
	2.0mΩ @ V <sub>GS</sub> = 10V	25A
30V	2.1mΩ @ V <sub>GS</sub> = 8V	20A
	2.6mΩ @ V <sub>GS</sub> = 4.5V	18A

## Description

This new generation MOSFET is designed to minimize the on-state resistance ( $R_{SS(ON)}$ ) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

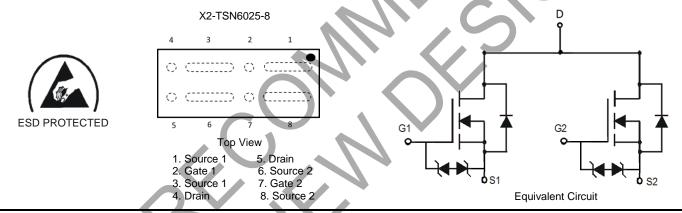
- Battery Management
- Load Switch
- Battery Protection

### Features

- CSP with Footprint 6mm × 2.5mm
- Height = 0.30mm (Typical) for Low Profile
- ESD Protection of Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/guality/product-definitions/</u>

### **Mechanical Data**

- Package: X2-TSN6025-8
- Terminal Connections: See Diagram Below
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu or NiAu. Solderable per MIL-STD-202, Method 208
- Weight: 0.0012 grams (Approximate)



## Ordering Information (Note 4)

	Part Number	Package	Packing					
	Fait Nulliber	Гаскауе	Qty.	Carrier				
	DMN3003LCA8-7	X2-TSN6025-8	3000	Tape & Reel				
Notes:	Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.							

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See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



OG = Product Type Marking Code

YW = Date Code Marking

Y or  $\overline{Y}$  = Year (ex: 1 = 2021)

W or  $\overline{W}$  = Week (ex: a = Week 27; z Represents Week 52 and 53)

#### Date Code Kev

Year	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	1	2	3	4	5	6	7	8	9	0	1	2

Week	1-26	27-52	53
Code	A-Z	a-z	Z



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Source-Source Voltage	V <sub>SSS</sub>	30	V
Gate-Source Voltage	V <sub>GSS</sub>	±20	V
Continuous Source Current (Note 5) V <sub>GS</sub> = 10V	Is	25 20	А
Continuous Source Current (Note 5) $V_{GS}$ = 4.5V	١ <sub>S</sub>	18 14	А
Pulsed Source Current (Note 6)	I <sub>SM</sub>	144	А

## **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 7)	PD	1.4	W
Thermal Resistance, Junction to Ambient $@T_A = +25$ °C (Note 7)	R <sub>0JA</sub>	91.8	°C/W
Power Dissipation (Note 5)	PD	2.5	W
Thermal Resistance, Junction to Ambient $@T_A = +25^{\circ}C$ (Note 5)	R <sub>0JA</sub>	50.3	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

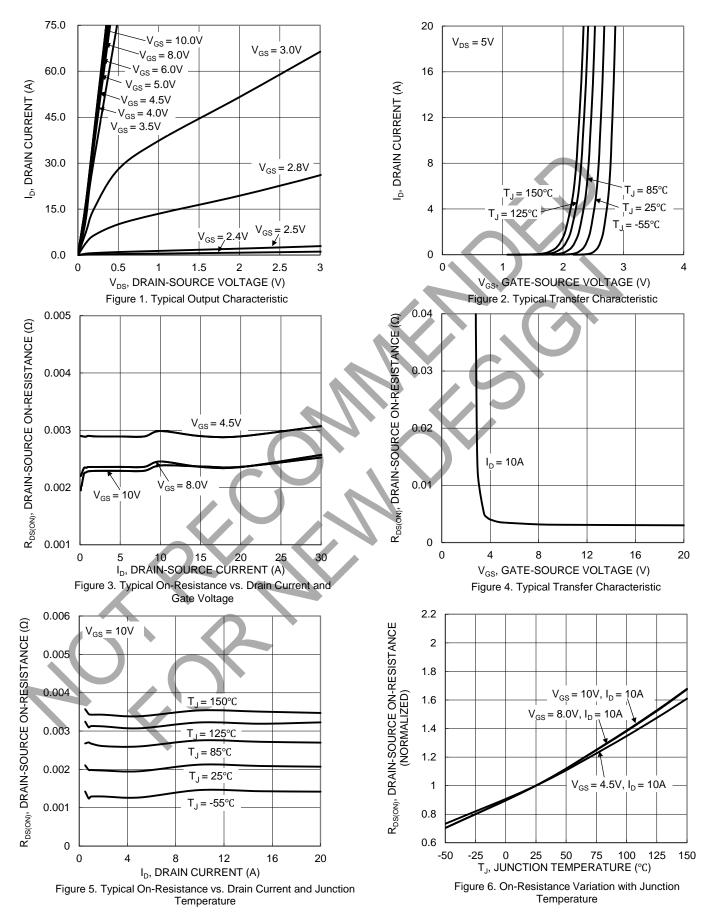
Characteristic	Crimeland		Tur	Aller	Unit	Test Condition
	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						1
Source-Source Breakdown Voltage	BV <sub>SSS</sub>	30	_		V	$V_{GS} = 0V, I_S = 1mA$
Zero Gate Voltage Drain Current T <sub>J</sub> = +25°C	Isss	_	—	1	μA	$V_{SS} = 24V, V_{GS} = 0V$
Gate-Source Leakage	lgss		—	±10	μA	$V_{GS} = \pm 20V, V_{SS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.3		2.2	V	$Vss = 10V, I_S = 1mA$
		1.5	2.0	2.6		$V_{GS} = 10V, I_{S} = 10A$
Static Source-Source On-Resistance	Rss(ON)	1.6	2.1	3.3	mΩ	$V_{GS} = 8V, I_{S} = 10A$
		2.2	2.6	5.1		$V_{GS} = 4.5V, I_{S} = 10A$
Diode Forward Voltage	Vss	→ −		1.2	V	$V_{GS} = 0V, I_{S} = 10A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	3722	_		
Output Capacitance	Coss	—	637	_	pF	V <sub>SS</sub> = 15V, V <sub>GS</sub> = 0V, f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	_	160	_		I = 1.00012
Total Gate Charge	Qg	—	45.5	_		
Gate-Source Charge	Q <sub>gs</sub>	—	14.3	_	nC	$V_{SS} = 15V, V_{GS} = 4.5V,$
Gate-Drain Charge	Q <sub>gd</sub>	_	14.3	_	nc	I <sub>S</sub> = 10A
Gate Charge at V <sub>TH</sub>	Q <sub>G(TH)</sub>	—	9.6	_		
Turn-On Delay Time	t <sub>D(ON)</sub>	_	0.6			
Turn-On Rise Time	t <sub>R</sub>	—	1.1	_		$V_{SS} = 15V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t <sub>D(OFF)</sub>		5.9		μs	I <sub>S</sub> = 10A
Turn-Off Fall Time	tF	_	2.9			

Notes:

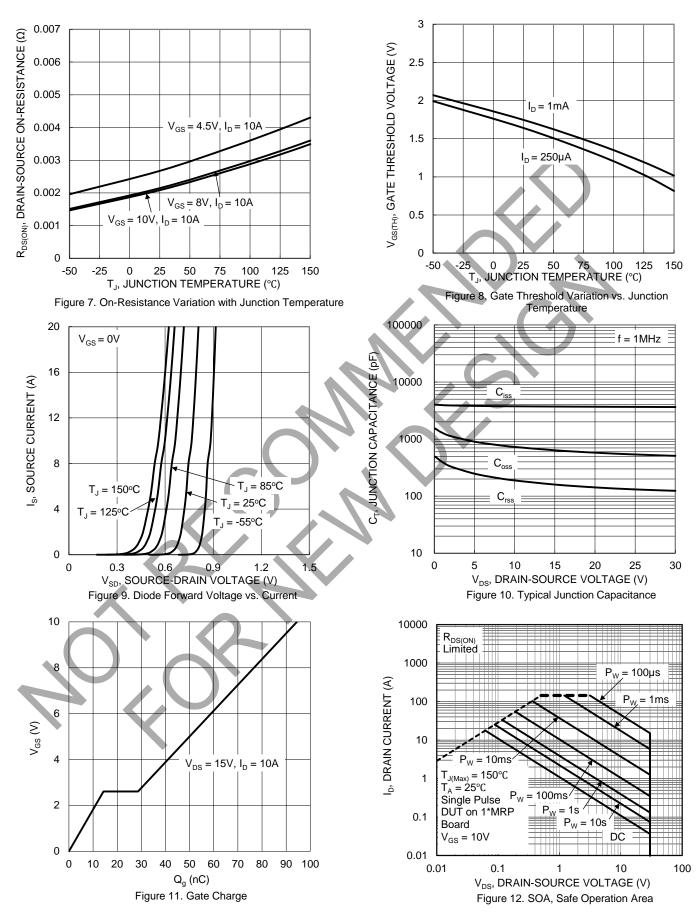
5. Device mounted on FR-4 material with 1inch<sup>2</sup> (6.45cm<sup>2</sup>), 2oz. (0.071mm thick) Cu.
6. Repetitive rating, pulse width limited by junction temperature.
7. Device mounted on FR-4 PCB with minimum recommended pad layout, single sided.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to production testing.



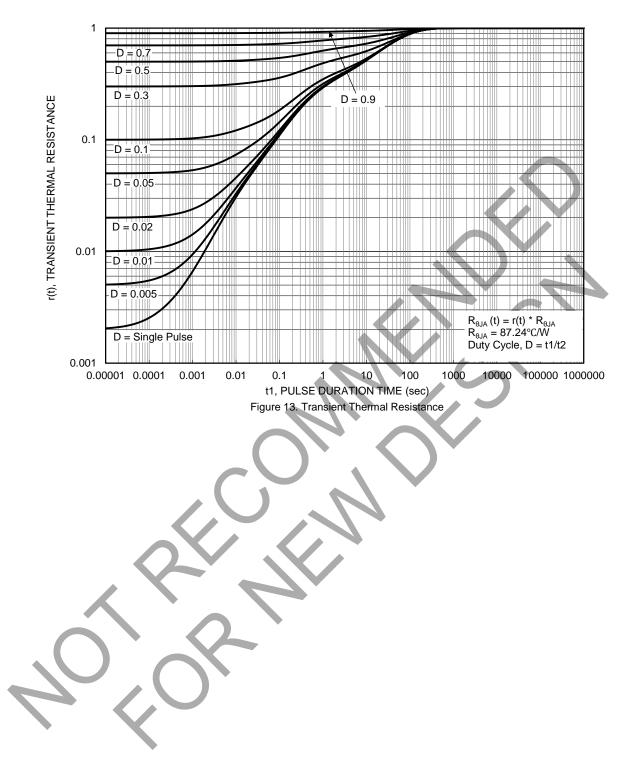
## DMN3003LCA8







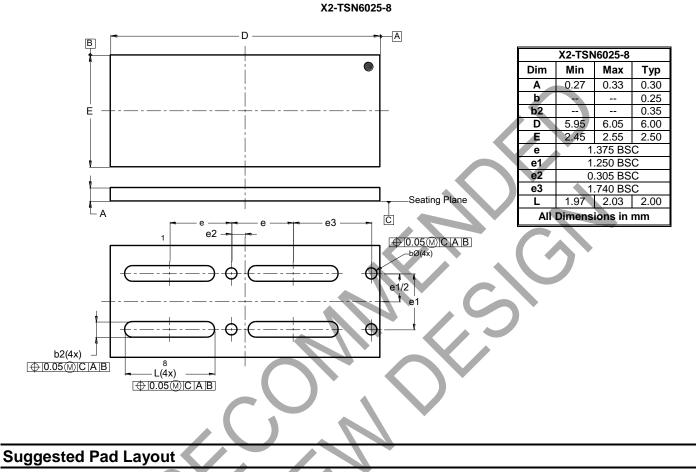




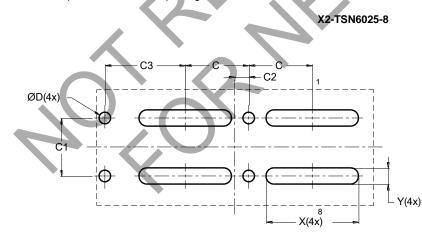


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.



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Dimensions	Value (in mm)			
С	1.375			
C1	1.250			
C2	0.305			
C3	1.740			
D	0.250			
Х	2.000			
Y	0.350			



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